

**VC-TCXO / TCXO**  
**ULTRA HIGH STABILITY**

**TG5032CDN**  
**TG5032SDN**



Product Number (please contact us)  
TG5032CDN :X1G005061xxxxxx  
TG5032SDN :X1G005071xxxxxx



Actual size



- Frequency range : 10 MHz to 50 MHz
- Supply voltage : 3.3 V Typ. / 5.0V Typ.
- Frequency / temperature characteristics :  $\pm 0.1 \times 10^{-6}$  Max. \*1
- Frequency aging :  $\pm 0.02 \times 10^{-6}$  Max./24 hours \*2
- External dimensions: 5.0 x 3.2 x 1.45 mm (4 pads)
- Applications : FemtoCell, Small Cells
- Features : Ultra high stability

**Specifications (characteristics)**

Item	Symbol	TG5032CDN (CMOS output)		TG5032SDN(Clipped sine wave)		Conditions / Remarks
		VC-TCXO	TCXO	VC-TCXO	TCXO	
Output frequency range	f <sub>o</sub>	10 MHz to 50 MHz				Standard frequency
Supply voltage	V <sub>CC</sub>	19.2, 26, 30.72, 40 MHz				
Storage temperature	T <sub>stg</sub>	C: 3.3 V $\pm 5\%$ , H: 5.0 V $\pm 5\%$ (Supply voltage range :2.7 V to 5.5 V)				Storage as single product
Operating temperature	T <sub>use</sub>	-40 °C to +90 °C				Standard temp. range
Frequency tolerance	f <sub>tol</sub>	A: 0 °C to +70 °C				After reflow, +25 °C
Frequency/temperature Characteristics *1	f <sub>o</sub> -Tc	$\pm 2.0 \times 10^{-6}$ Max.				A: 0 to +70 °C (Standard spec.)
Frequency/load coefficient	f <sub>o</sub> -Load	A: $\pm 0.1 \times 10^{-6}$ Max. / A: 0 to +70 °C (standard spec.)		H: $\pm 0.25 \times 10^{-6}$ Max. / G: -40 to +85 °C		Load $\pm 10\%$
		$\pm 0.1 \times 10^{-6}$ Max. (10 MHz $\leq$ f <sub>o</sub> $\leq$ 40 MHz)		$\pm 0.2 \times 10^{-6}$ Max. (40 MHz $<$ f <sub>o</sub> $\leq$ 50 MHz)		
Frequency/voltage coefficient	f <sub>o</sub> -Vcc	$\pm 0.1 \times 10^{-6}$ Max. (10 MHz $\leq$ f <sub>o</sub> $\leq$ 40 MHz)		$\pm 0.2 \times 10^{-6}$ Max. (40 MHz $<$ f <sub>o</sub> $\leq$ 50 MHz)		Vcc $\pm 5\%$
		$\pm 0.1 \times 10^{-6}$ Max. (10 MHz $\leq$ f <sub>o</sub> $\leq$ 40 MHz)		$\pm 0.2 \times 10^{-6}$ Max. (40 MHz $<$ f <sub>o</sub> $\leq$ 50 MHz)		
Frequency aging *2	f <sub>age</sub>	$\pm 0.02 \times 10^{-6}$ Max.				+25 °C, 24h
		$\pm 1.0 \times 10^{-6}$ Max.				+25 °C, First year
Current consumption	I <sub>CC</sub>	5.0 mA Max. / 6.0 mA Max.		5.0 mA Max.		10 MHz $\leq$ f <sub>o</sub> $\leq$ 26 MHz (3.3V / 5.0V)
		6.0 mA Max. / 8.0 mA Max.				26 MHz $<$ f <sub>o</sub> $\leq$ 40 MHz (3.3V / 5.0V)
		8.0 mA Max. / 10.0 mA Max.				40 MHz $<$ f <sub>o</sub> $\leq$ 50 MHz (3.3V / 5.0V)
Input resistance	R <sub>in</sub>	100 kΩ Min.	—	100 kΩ Min.	—	Vc- GND (DC)
Frequency control range	f <sub>cont</sub>	$\pm 5 \times 10^{-6}$ to $\pm 10 \times 10^{-6}$	—	$\pm 5 \times 10^{-6}$ to $\pm 10 \times 10^{-6}$	—	D : Vc=1.5 V $\pm$ 1.0 V at V <sub>CC</sub> =3.3 V E: Vc=1.65 V $\pm$ 1.0 V at V <sub>CC</sub> =3.3 V H: Vc=2.5 V $\pm$ 2.0 V at V <sub>CC</sub> =5.0 V
Frequency change polarity	—	Positive polarity	—	Positive polarity	—	
Symmetry	SYM	45 % to 55 %		—		50 % Vcc level, L_CMOS $\leq$ 15 pF
Output voltage	V <sub>OH</sub>	90 % Vcc Min.		—		
	V <sub>OL</sub>	10 % Vcc Max.		—		
Output level	V <sub>PP</sub>	—		0.8 V Min.		Peak to Peak
Rise time / Fall time	t <sub>r</sub> / t <sub>f</sub>	8.0 ns Max.		—		10 % Vcc to 90 % Vcc level, Load:15 pF
Start-up time	t <sub>str</sub>	5.0 ms Max.				T=0 at 90% Vcc
Output load condition	Load	15 pF		10 kΩ/10 pF		

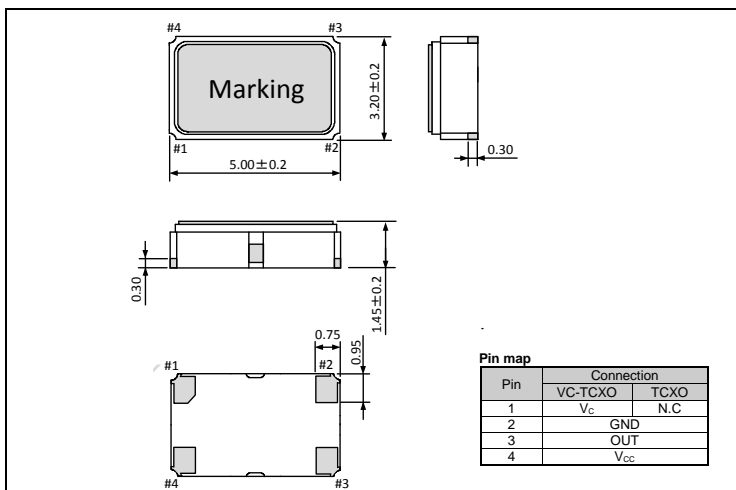
\* Note : Please contact us for requirements not listed in this specification. \*1 Based on frequency at (fmax+fmin)/2. \*2 After 48 hours operating

Product Name **TG5032 C DN 19.200000MHz C A A N D A**  
(Standard form) ① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨

- ① Model ② Output (C: CMOS, S: Clipped sine wave) ③ Frequency ④ Supply voltage (C: 3.3 V Typ.)
- ⑤ Frequency / temperature characteristics (A:  $\pm 0.1 \times 10^{-6}$  Max.) ⑥ Operating temperature (A: 0 °C to +70 °C)
- ⑦ OE function (N: Non) ⑧ Vc function (A: Vc =any, D: Vc =1.5 V, E: Vc =1.65 V, H: Vc =2.5 V, N: Non)
- ⑨ Internal identification code ("A" is default)

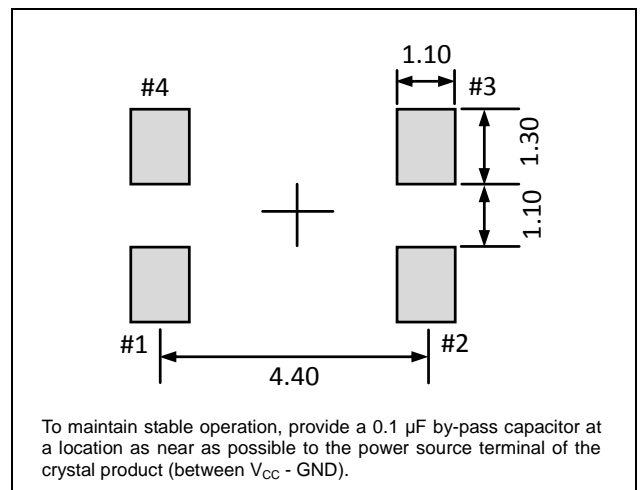
**External dimensions**

(Unit :mm)



**Footprint (Recommended)**

(Unit :mm)



## PROMOTION OF ENVIRONMENTAL MANAGEMENT SYSTEM CONFORMING TO INTERNATIONAL STANDARDS

At Seiko Epson, all environmental initiatives operate under the Plan-Do-Check-Action (PDCA) cycle designed to achieve continuous improvements. The environmental management system (EMS) operates under the ISO 14001 environmental management standard.

All of our major manufacturing and non-manufacturing sites, in Japan and overseas, completed the acquisition of ISO 14001 certification.

ISO 14000 is an international standard for environmental management that was established by the International Standards Organization in 1996 against the background of growing concern regarding global warming, destruction of the ozone layer, and global deforestation.





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### ► Explanation of the mark that are using it for the catalog

	► Pb free.
	► Complies with EU RoHS directive. *About the products without the Pb-free mark. Contains Pb in products exempted by EU RoHS directive. (Contains Pb in sealing glass, high melting temperature type solder or other.)
	► Designed for automotive applications such as Car Multimedia, Body Electronics, Remote Keyless Entry etc.
	► Designed for automotive applications related to driving safety (Engine Control Unit, Air Bag, ESC etc ).

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